

TOSHIBA Intelligent Power Module Silicon N Channel IGBT

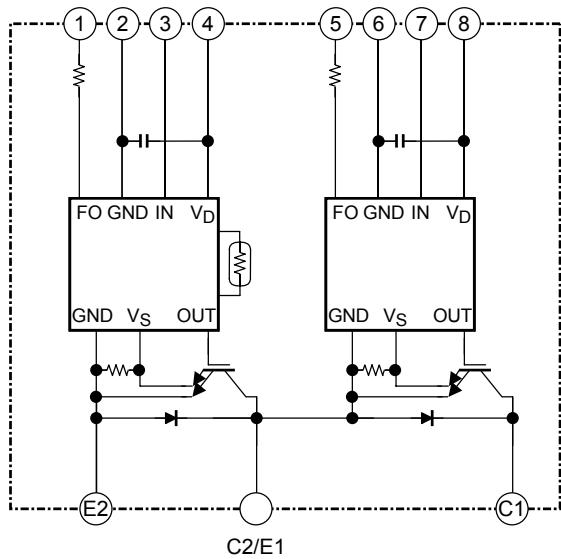
# MIG300J2CSB1W (600V/300A 2in1)

High Power Switching Applications

Motor Control Applications

- Integrates inverter power circuits and control circuits (IGBT drive unit, units for protection against short-circuit current, overcurrent, undervoltage and overtemperature) into a single package.
- The electrodes are isolated from the case.
- Low thermal resistance
- $V_{CE}(\text{sat}) = 1.9 \text{ V (typ.)}$
- UL recognized: File No.E87989
- Weight: 278 g (typ.)

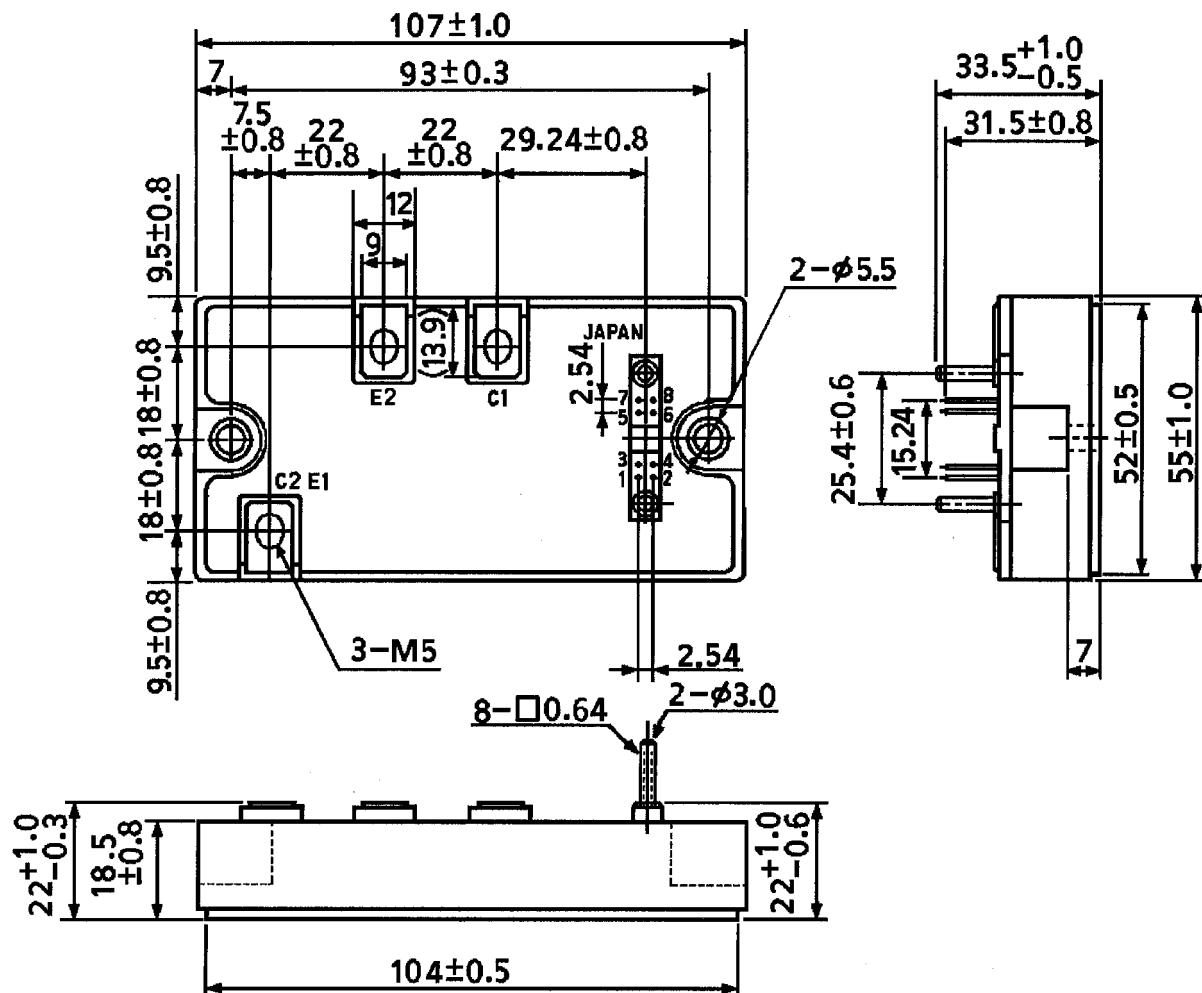
## Equivalent Circuit



- |           |            |           |              |
|-----------|------------|-----------|--------------|
| 1. FO (L) | 2. GND (L) | 3. IN (L) | 4. $V_D$ (L) |
| 5. FO (H) | 6. GND (H) | 7. IN (H) | 8. $V_D$ (H) |

## Package Dimensions: TOSHIBA 2-108H1A

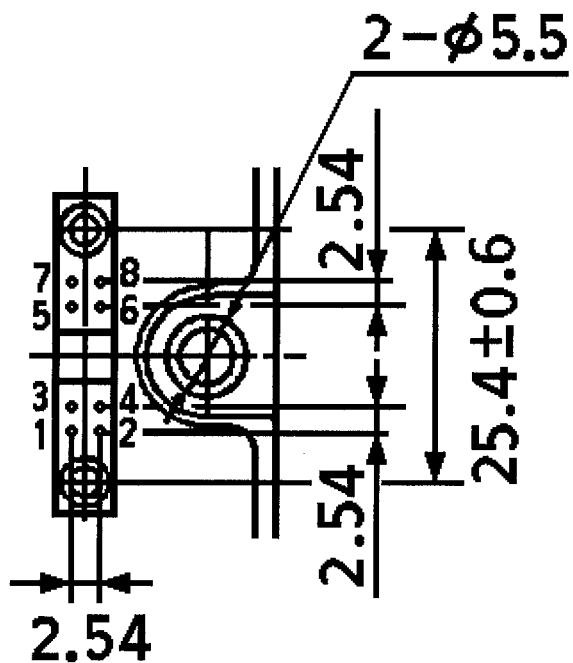
Unit: mm



1. FO (L)    2. GND (L)    3. IN (L)    4. V<sub>D</sub> (L)
5. FO (H)    6. GND (H)    7. IN (H)    8. V<sub>D</sub> (H)

**Signal Terminal Layout**

Unit: mm



- |           |            |           |                       |
|-----------|------------|-----------|-----------------------|
| 1. FO (L) | 2. GND (L) | 3. IN (L) | 4. V <sub>D</sub> (L) |
| 5. FO (H) | 6. GND (H) | 7. IN (H) | 8. V <sub>D</sub> (H) |

**Maximum Ratings ( $T_j = 25^\circ\text{C}$ )**

Stage	Characteristics	Condition	Symbol	Rating	Unit
Inverter	Supply voltage	P-N power terminal	$V_{CC}$	450	V
	Collector-emitter voltage	—	$V_{CES}$	600	V
	Collector current	$T_c = 25^\circ\text{C}$ , DC	$I_C$	300	A
	Forward current	$T_c = 25^\circ\text{C}$ , DC	$I_F$	300	A
	Collector power dissipation	$T_c = 25^\circ\text{C}$	$P_C$	1600	W
	Junction temperature	—	$T_j$	150	$^\circ\text{C}$
Control	Control supply voltage	$V_D$ -GND terminal	$V_D$	20	V
	Input voltage	IN-GND terminal	$V_{IN}$	20	V
	Fault output voltage	FO-GND terminal	$V_{FO}$	20	V
	Fault output current	FO sink current	$I_{FO}$	10	mA
Module	Operating temperature	—	$T_c$	-20~+100	$^\circ\text{C}$
	Storage temperature	—	$T_{stg}$	-40~+125	$^\circ\text{C}$
	Isolation voltage	AC 1 min	$V_{ISO}$	2500	V
	Screw torque	M5	—	3	N·m

**Electrical Characteristics****1. Inverter stage**

Characteristics	Symbol	Test Condition		Min	Typ.	Max	Unit
Collector cut-off current	$I_{CEX}$	$V_{CE} = 600 \text{ V}$	$T_j = 25^\circ\text{C}$	—	—	1	mA
			$T_j = 125^\circ\text{C}$	—	—	10	
Collector-emitter saturation voltage	$V_{CE}$ (sat)	$V_D = 15 \text{ V}$ $I_C = 300 \text{ A}$ $V_{IN} = 15 \text{ V} \rightarrow 0 \text{ V}$	$T_j = 25^\circ\text{C}$	1.6	1.9	2.3	V
			$T_j = 125^\circ\text{C}$	—	2.1	—	
Forward voltage	$V_F$	$I_F = 300 \text{ A}, T_j = 25^\circ\text{C}$		—	2.1	2.5	V
Switching time	$t_{on}$	$V_{CC} = 300 \text{ V}, I_C = 300 \text{ A}$ $V_D = 15 \text{ V}, V_{IN} = 15 \text{ V} \leftrightarrow 0 \text{ V}$ $T_j = 25^\circ\text{C}$ , Inductive load	(Note 1)	—	2.0	3.0	$\mu\text{s}$
	$t_c$ (on)			—	0.4	—	
	$t_{rr}$			—	0.2	—	
	$t_{off}$			—	1.5	2.5	
	$t_c$ (off)			—	0.25	—	

Note 1: Switching time test circuit &amp; timing chart

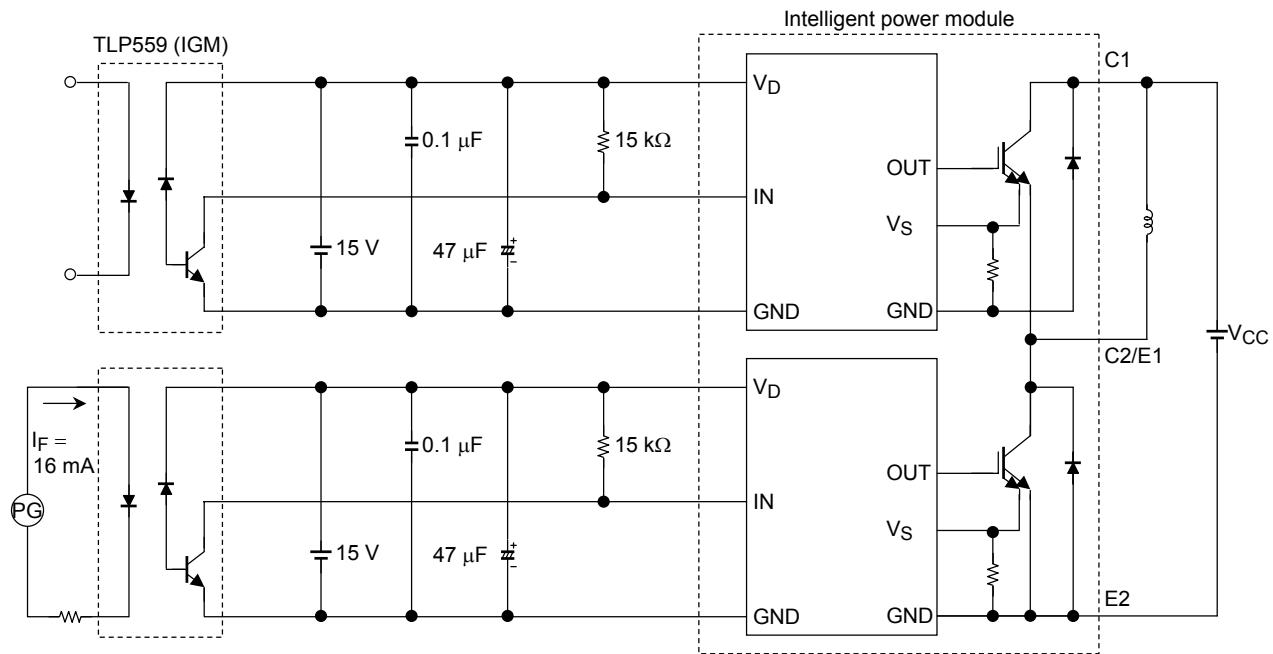
## 2. Control stage ( $T_j = 25^\circ\text{C}$ )

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Control circuit current	High side	$I_D(\text{H})$	$V_D = 15 \text{ V}$	—	13	17	mA
	Low side	$I_D(\text{L})$		—	13	17	
Input on signal voltage		$V_{IN}(\text{on})$	$V_D = 15 \text{ V}$	1.4	1.6	1.8	V
Input off signal voltage		$V_{IN}(\text{off})$		2.2	2.5	2.8	
Fault output current	Protection	$I_{FO}(\text{on})$	$V_D = 15 \text{ V}$	—	10	12	mA
	Normal	$I_{FO}(\text{off})$		—	—	0.1	
Overcurrent protection trip level	Inverter	OC	$V_D = 15 \text{ V}, T_j \leq 125^\circ\text{C}$	480	—	—	A
Short-circuit protection trip level	Inverter	SC	$V_D = 15 \text{ V}, T_j \leq 125^\circ\text{C}$	480	—	—	A
Overcurrent cut-off time		$t_{off}(\text{OC})$	$V_D = 15 \text{ V}$	—	5	—	$\mu\text{s}$
Overtemperature protection	Trip level	OT	Case temperature	110	118	125	$^\circ\text{C}$
	Reset level	OTr		—	98	—	
Control supply under voltage protection	Trip level	UV	—	11.0	12.0	12.5	V
	Reset level	UVr		12.0	12.5	13.0	
Fault output pulse width		$t_{FO}$	$V_D = 15 \text{ V}$	1	2	3	ms

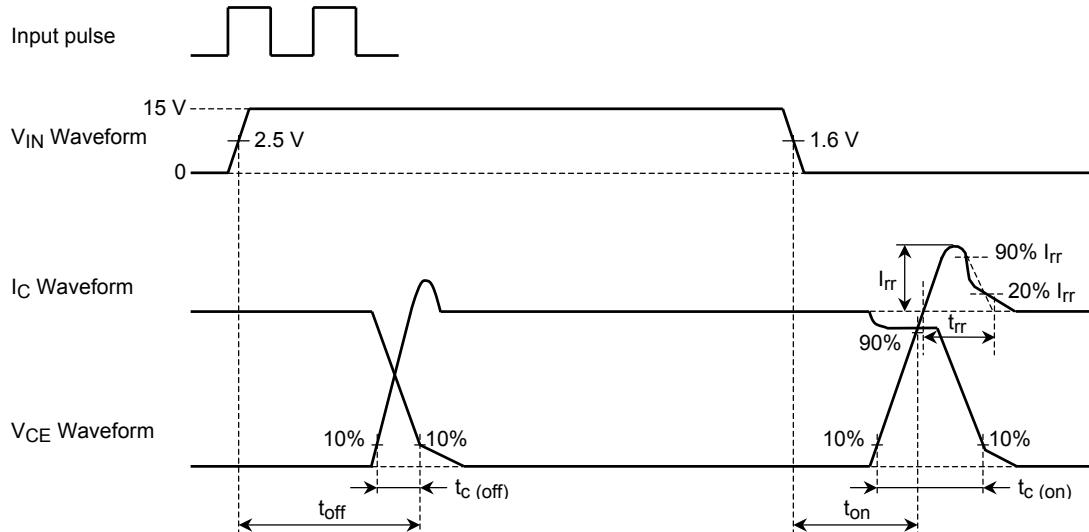
## 3. Thermal resistance ( $T_c = 25^\circ\text{C}$ )

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Junction to case thermal resistance	$R_{th}(j-c)$	IGBT		—	—	0.078	$^\circ\text{C/W}$
		FRD		—	—	0.130	
Case to fin thermal resistance		$R_{th}(c-f)$	Compound is applied	—	0.017	—	$^\circ\text{C/W}$

## Switching Time Test Circuit



## Timing Chart

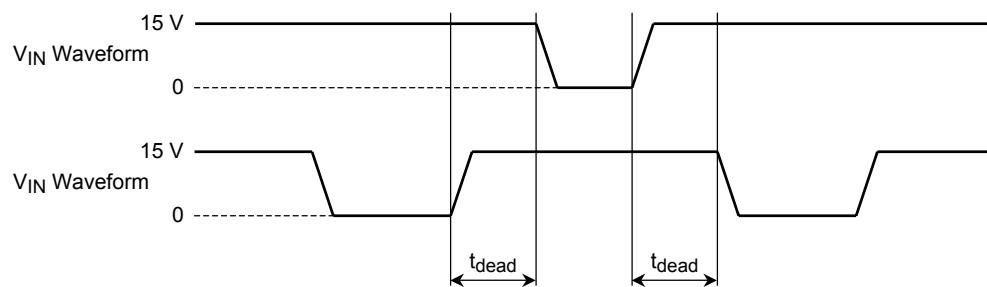


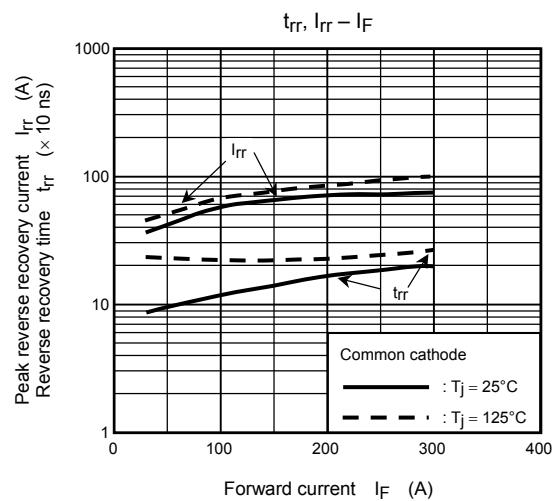
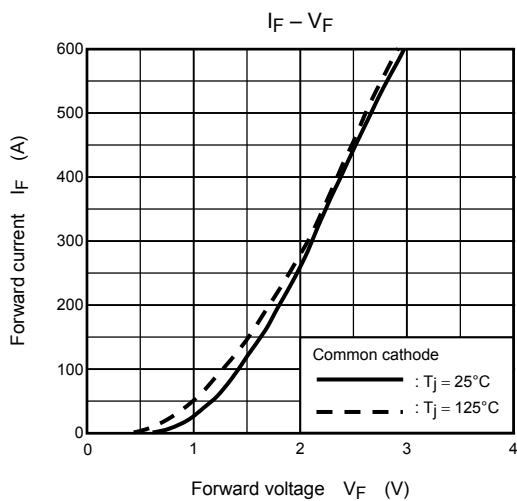
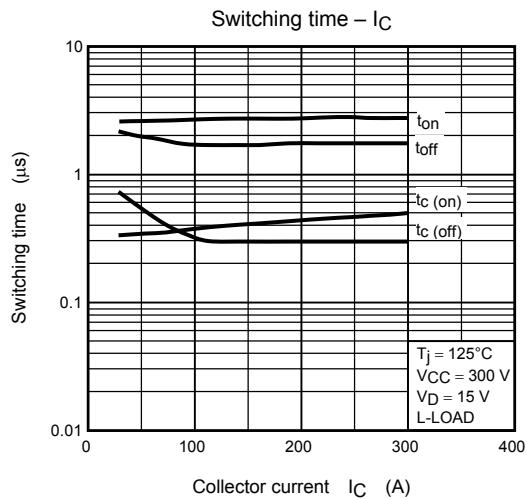
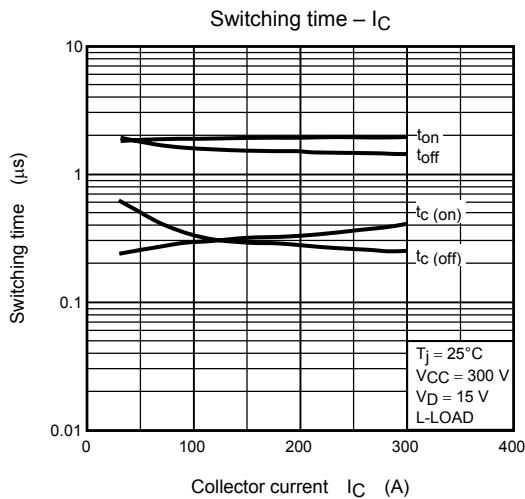
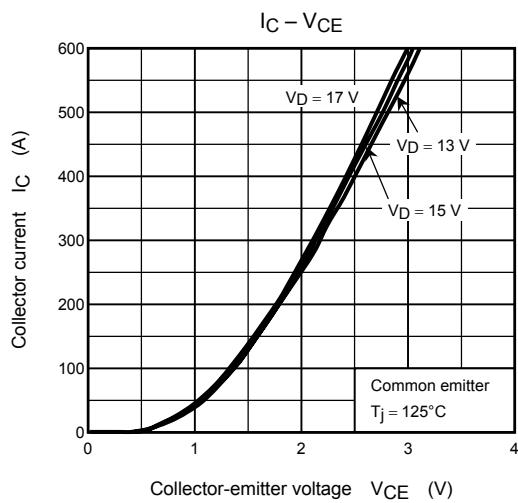
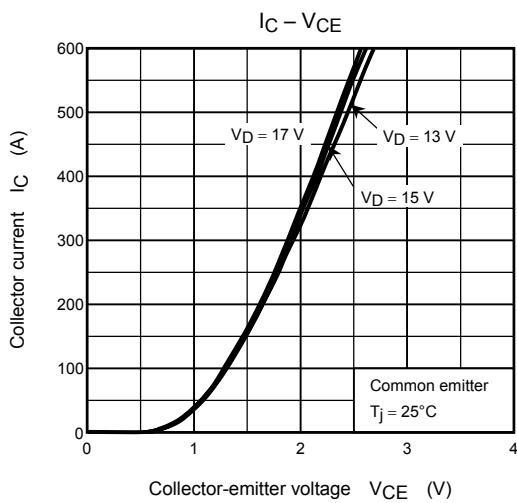
#### 4. Recommended conditions for application

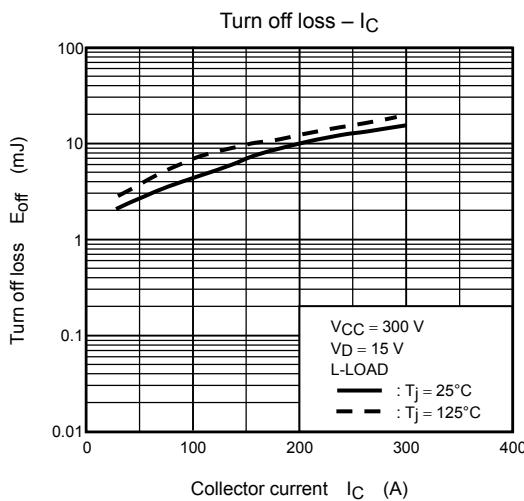
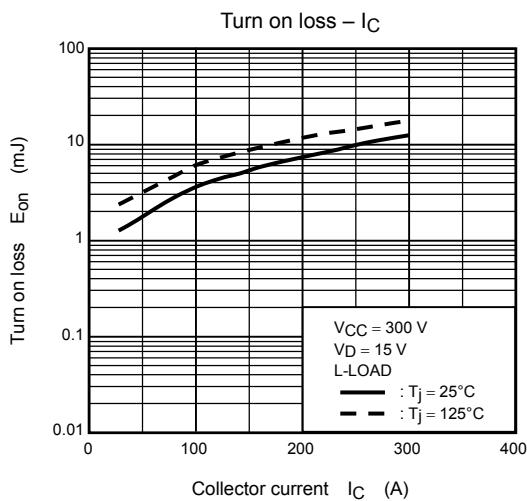
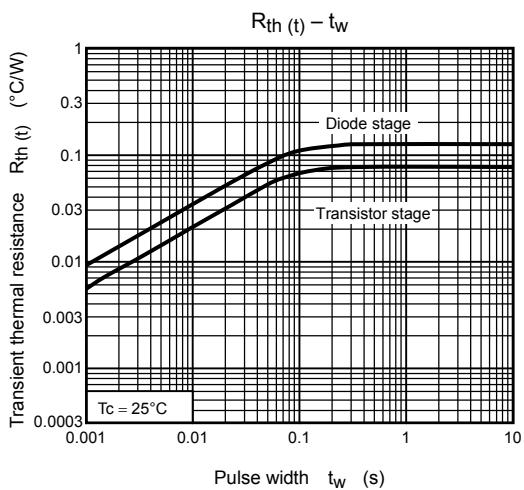
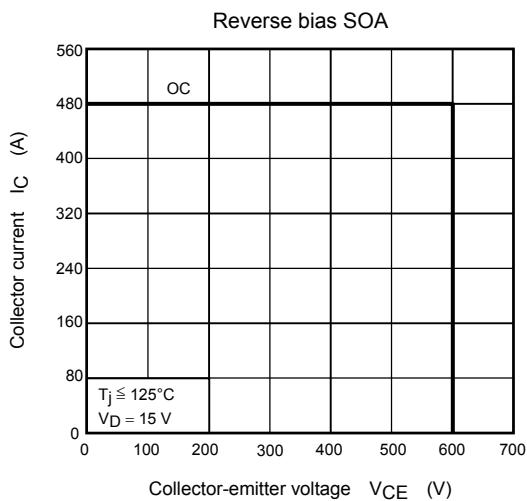
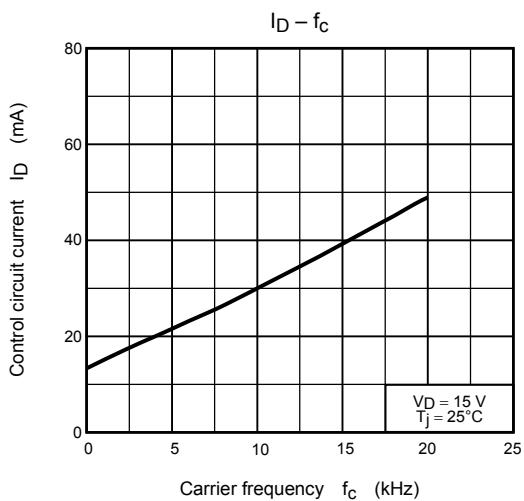
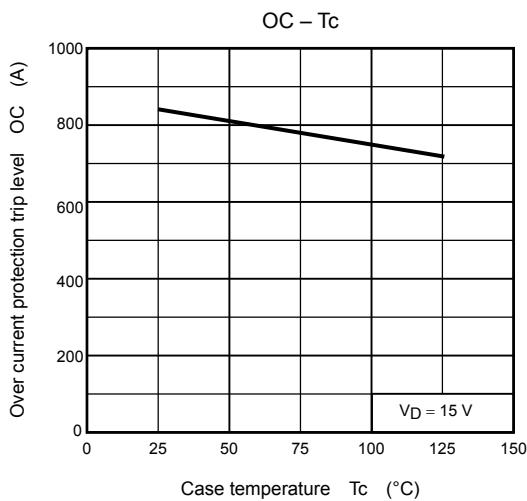
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Supply voltage	V <sub>CC</sub>	P-N power terminal	—	300	400	V
Control supply voltage	V <sub>D</sub>	V <sub>D</sub> -GND signal terminal	13.5	15	16.5	V
Carrier frequency	f <sub>c</sub>	PWM control	—	—	20	kHz
Dead time	t <sub>dead</sub>	Switching time test circuit (see page.6) (Note 2)	5	—	—	μs

Note 2: The table lists Dead time requirements for the module input, excluding photocoupler delays. When specifying dead time requirements for the photocoupler input, please add photocoupler delays to the dead time given above.

#### Dead Time Timing Chart







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